



**The Abdus Salam  
International Centre for Theoretical Physics**



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Characterization and Basic Understanding of Radiation Damage  
Mechanisms in Materials**

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**Electronic structure of UO<sub>2</sub>**

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# Electronic structure of $\text{UO}_2$

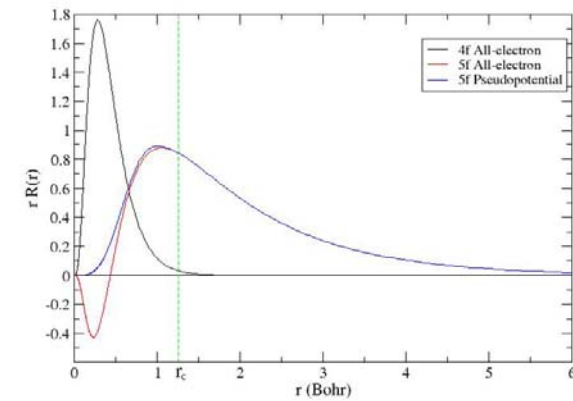
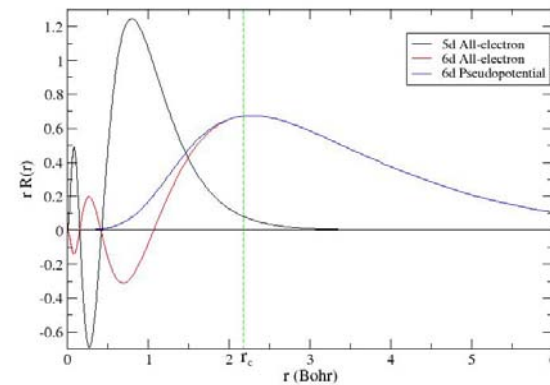
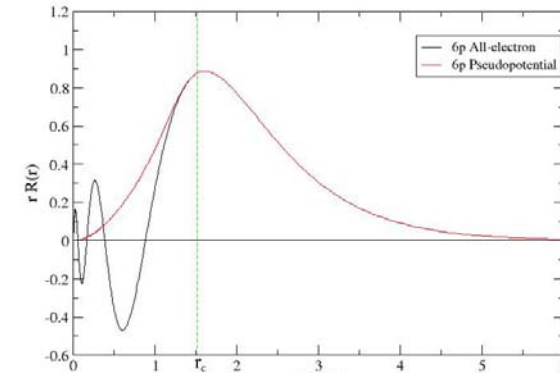
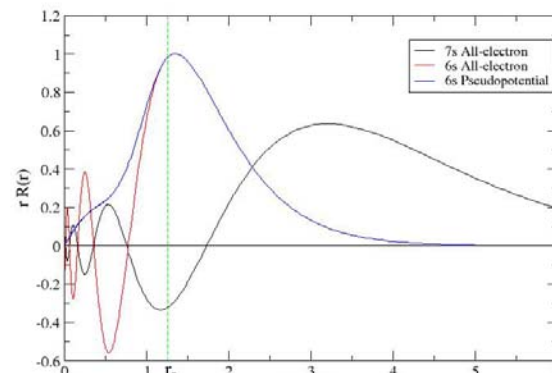
Using the quantum-espresso package  
(<http://www.quantum-espresso.org/>)

- Pseudopotentials
- Plane wave basis set

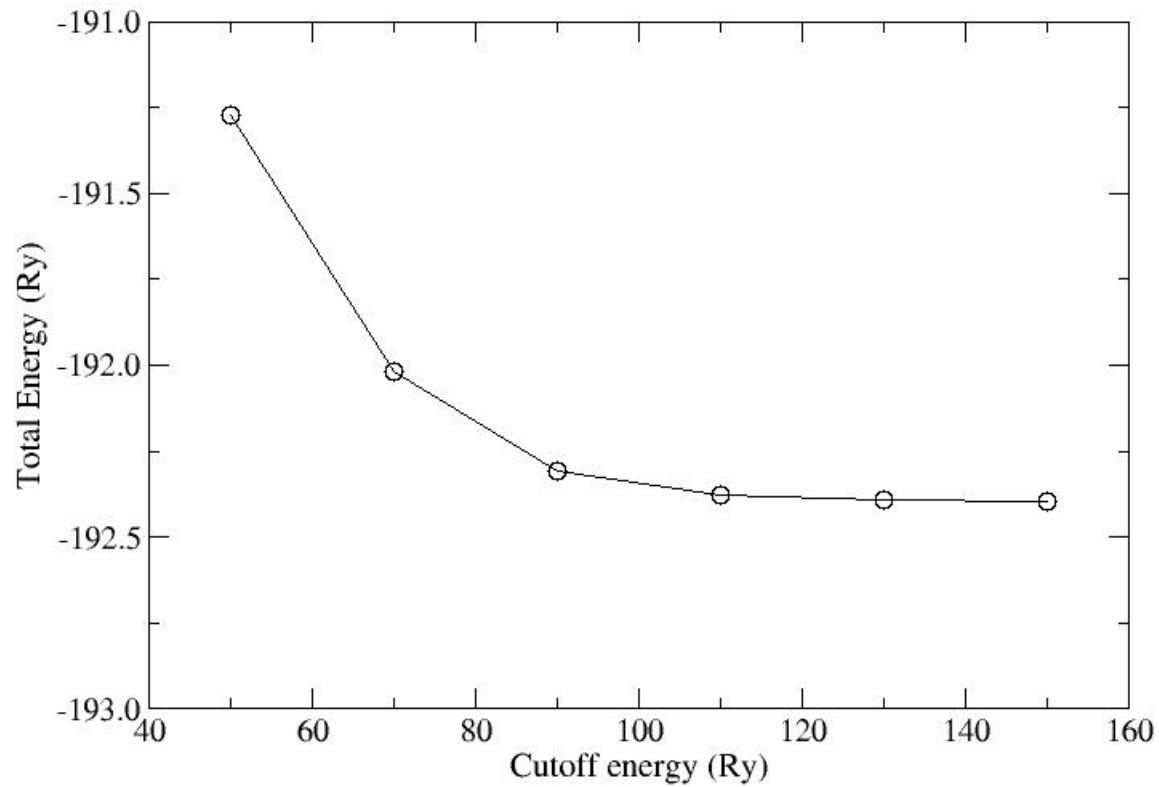
# Properties

- fluorite structure
- fcc, 3 atoms un unit cell
- Lattice constant = 10.26 Bohr
- Electronic insulator.  $E_g=2.1$  eV
- Electronic configuration of U:  $[\text{Rn}]7s^26d^15f^3$
- $\text{U}^{4+}$ :  $f^2$
- 5f-band partially occupied (2/7)
- $\text{UO}_2$ : splitted by crystal field:  $t_{1u}(3)+t_{2u}(3)+a_g(1)$
- Still partially occupied (2/3)
- Jahn-Teller distortion opens gap.

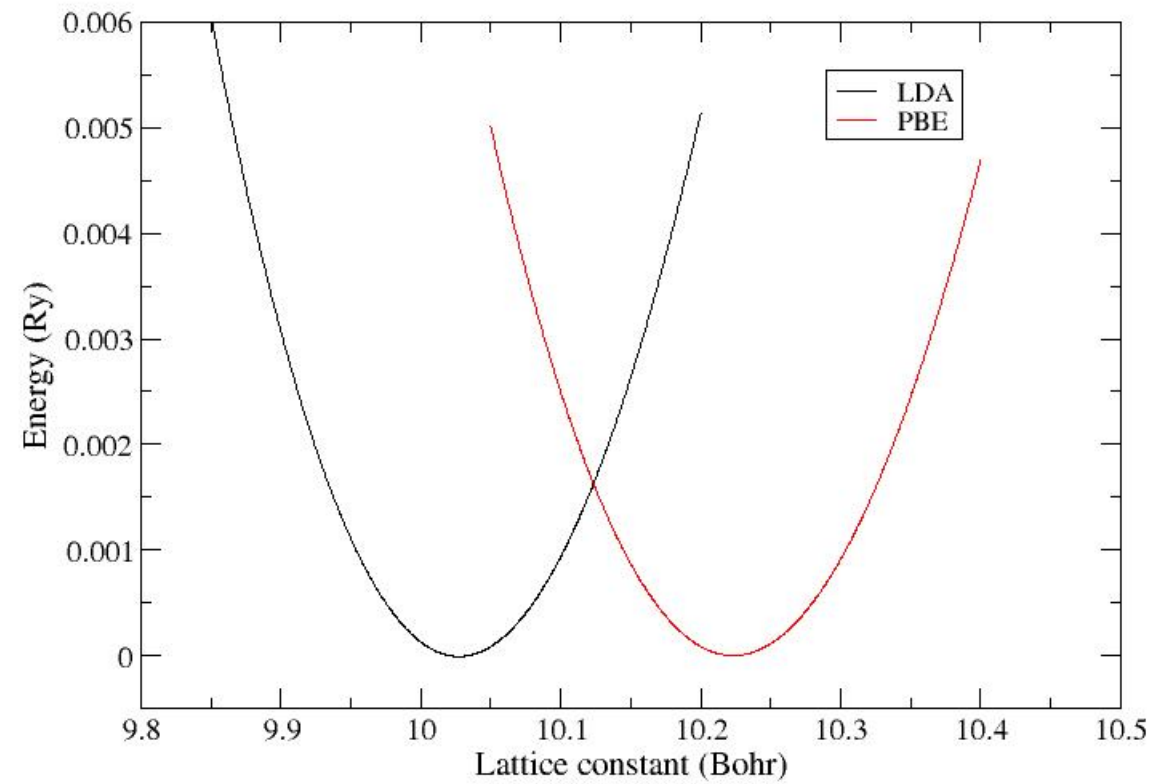
# Pseudopotential



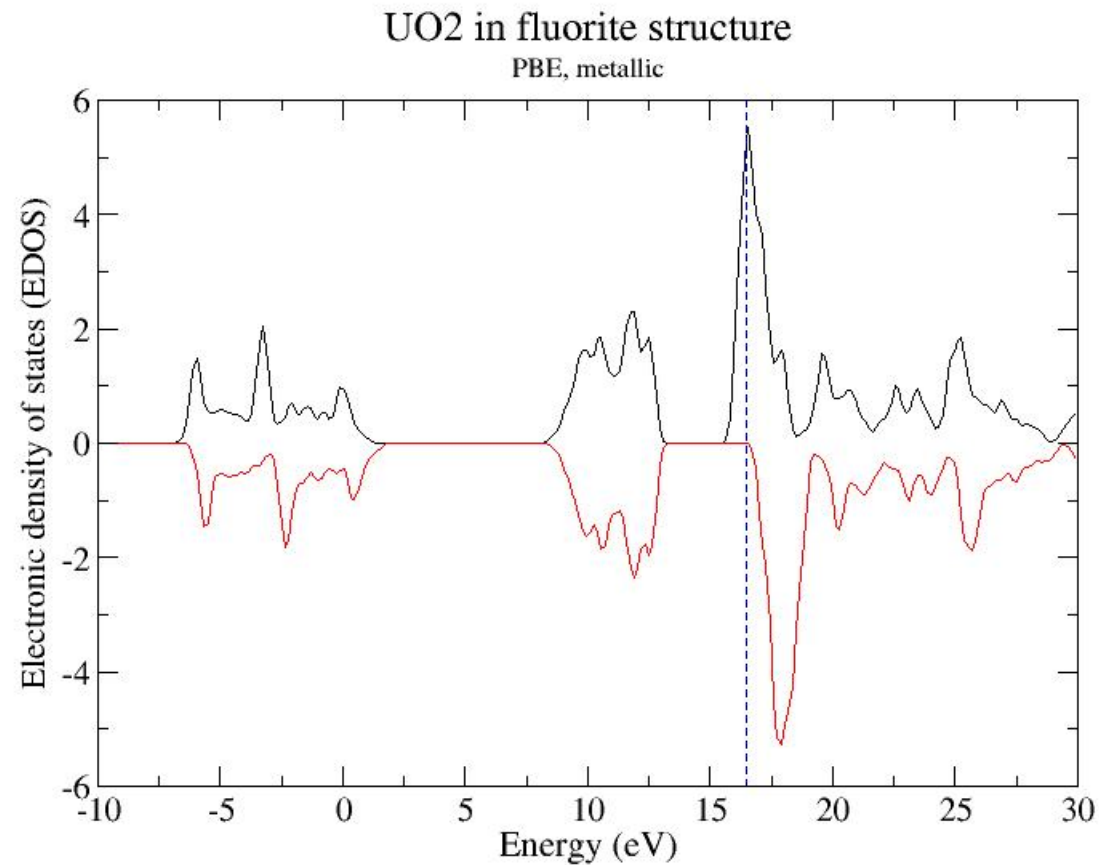
# Convergence with basis set size



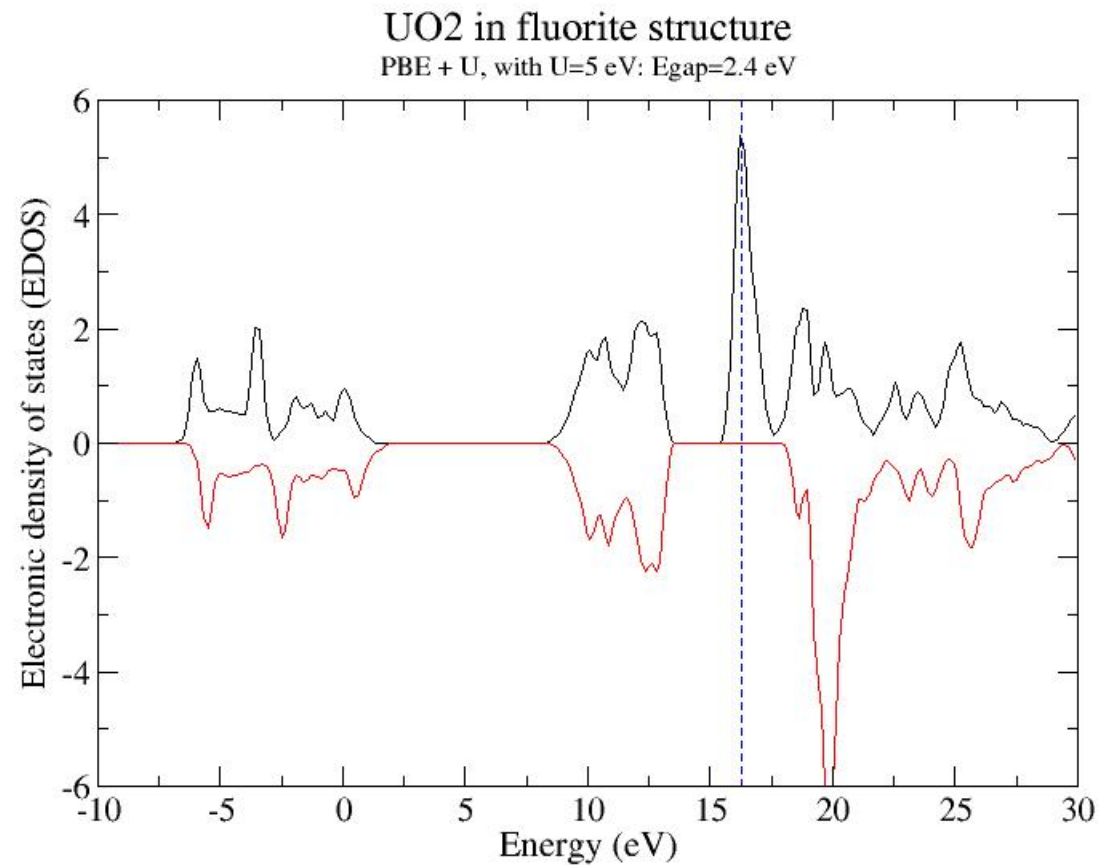
# Energy-volume curve



# GGA(PBE) density of states



# GGA+U density of states





# GGA+U density of states distorted

UO<sub>2</sub> in fluorite structure  
PBE + U, with U=5 eV: E<sub>gap</sub>=2.4 eV

